NSN 5962-01-168-0834

Memory Microcircuit - Page 1 of 1



low level

View Online at https://aerobasegroup.com/nsn/5962-01-168-0834

Body Length:		
0.840 inches		
Body Width:		
Between 0.220 ir	nches and 0.310 inches	
Body Height:		
0.185 inches		
Maximum Powe	r Dissipation Rating:	
739.0 milliwatts		
Operating Temp	ourature Range:	
-55.0/+125.0 deg	rees celsius	
Storage Tempu	rature Range:	
-65.0/+150.0 deg	rees celsius	
Features Provid	led:	
Monolithic and he	ermetically sealed and programmable and schottky and bipolar and 3-state output	
Inclosure Mater	ial:	
Ceramic and glas	55	
Inclosure Config	guration:	
Dual-in-line		
Output Logic Fo	orm:	
Transistor-diode-	resistor logic	
Input Circuit Pa	ttern:	
6 input		
Case Outline Sc	purce And Designator:	
D-2 mil-m-38510		
Terminal Surfac	e Treatment:	
Solder		
Voltage Rating	And Type Per Characteristic:	
5.5 volts powers	source	
Time Rating Per	Chacteristic:	
80.00 nanosecor	nds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, hi	igh to l
output		
Memory Device	Туре:	
Rom		
Terminal Type A	And Quantity:	
16 printed circuit		
Shelf Life:		
N/a		
Unit Of Measure		
Demilitarization	:	
Yes - demil/mli		
Fiig:		
A458a0		